HEX BUFFERS WITH OPEN DRAIN OUTPUTS

NEW PRODUCT

Description

The 74LV07A provides provides six independent buffers with open drain outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

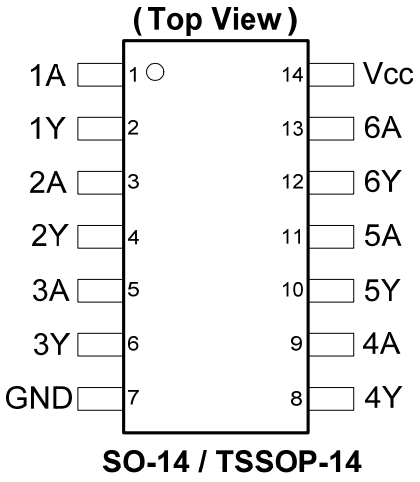
The gates perform the Boolean function:

$Y = A$

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks 12mA at V_{CC} = 4.5V
- CMOS low power consumption
- IOFF Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
  - Exceeds 200-V Machine Model (A115)
  - Exceeds 2000-V Human Body Model (A114)
  - Exceeds 1000-V Charged Device Model (C101)
  - Latch-Up Exceeds 100mA per JESD 78, Class I
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
  - PCs, networking, notebooks, ultrabooks, netbooks
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

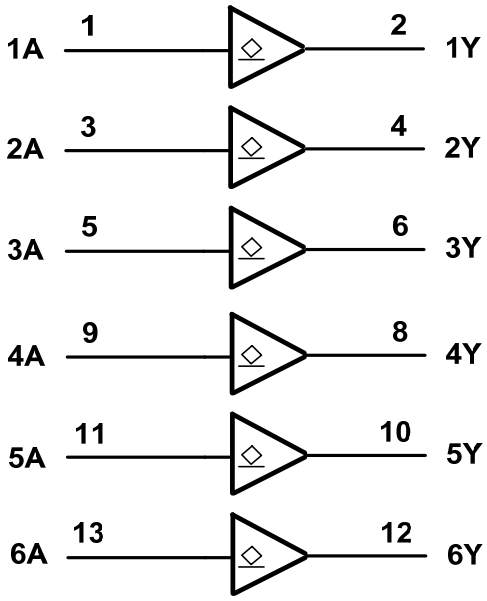
Click for Ordering Information

NEW PRODUCT

Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage

Logic Diagram



Function Table

Input	Output
A	Y
H	Z
L	L

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +7.0	V
V_I	Input Voltage Range (Note 4)	-0.5 to +7.0	V
I_{IK}	Input Clamp Current $V_I < 0V$	-20	mA
I_{OK}	Output Clamp Current $V_O < 0V$	-50	mA
I_O	Continuous Output Current $-0.5V < V_O$ V_{CC} $+0.5V$	- 25	mA
I_{CC}	Continuous Current Through V_{CC}	50	mA
I_{GND}	Continuous Current Through GND	-50	mA
T_J	Operating Junction Temperature	-40 to +150	°C
T_{STG}	Storage Temperature	-65 to +150	°C
P_{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

NEW PRODUCT

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply Voltage	—	2.0	5.5	V
V_I	Input Voltage	—	0	5.5	V
V_O	Output Voltage	—	0	5.5	V
I_{OL}	Low-Level Output Current	2.0V	—	50	µA
		2.3V to 2.7V	—	2	mA
		3.0V to 3.6V	—	6	mA
		4.5V to 5.5V	—	12	mA
Δt/ΔV	Input Transition Rise or Fall Rate	2.3V to 2.7V	—	200	ns/V
		3.0V to 3.6V	—	100	
		4.5V to 5.5V	—	20	
T_A	Operating Free-Air Temperature	—	-40	125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V_{CC}	T_A = -40°C to +85°C		T_A = -40°C to +125°C		Unit
				Min	Max	Min	Max	
V_{IH}	High-Level Input Voltage	—	2.0V	1.5	—	1.5	—	V
		—	2.3V to 2.7V	V_{CC} X 0.7	—	V_{CC} X 0.7	—	
		—	3.0V to 3.6V	V_{CC} X 0.7	—	V_{CC} X 0.7	—	
		—	4.5V to 5.5V	V_{CC} X 0.7	—	V_{CC} X 0.7	—	—
V_{IL}	Low-Level Input Voltage	—	2.0V	—	0.5	—	0.5	V
		—	2.3V to 2.7V	—	V_{CC} X 0.3	—	V_{CC} X 0.3	
		—	3.0V to 3.6V	—	V_{CC} X 0.3	—	V_{CC} X 0.3	
		—	4.5V to 5.5V	—	V_{CC} X 0.3	—	V_{CC} X 0.3	—
V_{OL}	Low-Level Output Voltage	I_{OL} = 50µA	2.0V to 5.5V	—	0.1	—	0.1	V
		I_{OL} = 2mA	2.3V	—	0.4	—	0.4	
		I_{OL} = 6mA	3.0V	—	0.44	—	0.44	
		I_{OL} = 12mA	4.5V	—	0.55	—	0.55	
I_{OFF}	Power Down Leakage Current	V_I or V_O = 0 to 5.5V	0V	—	5	—	5	µA
I_I	Input Current	V_I =GND or 5.5V	0 to 5.5V	—	±1	—	±1	µA
I_{CC}	Supply Current	V_I = GND or V_{CC} I_O=0	5.5V	—	20	—	20	µA

NEW PRODUCT

Switching Characteristics

V_{CC} = 2.5V ± 0.2V

Symbol	Parameter	Test Conditions	T_A = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{PLZ}	Propagation Delay A_N to Y_N	Figure 1 C_L = 15pF	—	6.6	10.4	1	13	1	13	ns
t_{PZL}			—	7.5	10.4	1	13	1	13	
t_{PLZ}		Figure 1 C_L = 50pF	—	11.1	15.2	1	18	1	18	ns
t_{PZL}			—	9.6	15.2	1	18	1	18	

V_{CC} = 3.3V ± 03 V

Symbol	Parameter	Test Conditions	T_A = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{PLZ}	Propagation Delay A_N to Y_N	Figure 1 C_L = 15pF	—	5	7.1	1	8.5	1	8.5	ns
t_{PZL}			—	5	7.1	1	8.5	1	8.5	
t_{PLZ}		Figure 1 C_L = 50pF	—	8.2	10.6	1	12	1	12	ns
t_{PZL}			—	6.6	10.6	1	12	1	12	

V_{CC} = 5.0V ± 0.5V

Symbol	Parameter	Test Conditions	T_A = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{PLZ}	Propagation Delay A_N to Y_N	Figure 1 C_L = 15pF	—	3.8	5.5	1	6.5	1	6.5	ns
t_{PZL}			—	3.4	5.5	1	6.5	1	6.5	
t_{PLZ}		Figure 1 C_L = 50 pF	—	5.7	7.5	1	8.5	1	8.5	ns
t_{PZL}			—	4.5	7.5	1	8.5	1	8.5	

Operating Characteristics

T_A = +25°C

Parameter		Test Conditions	V_{CC}	Typ	Unit
C_{pd}	Power Dissipation Capacitance per Gate	f = 10MHz C_L = 50pF	3.3V	2.9	pF
			5.0V	5.3	

Noise Characteristics

V_{CC} = 3V, C_L = 50pF, T_A = +25°C

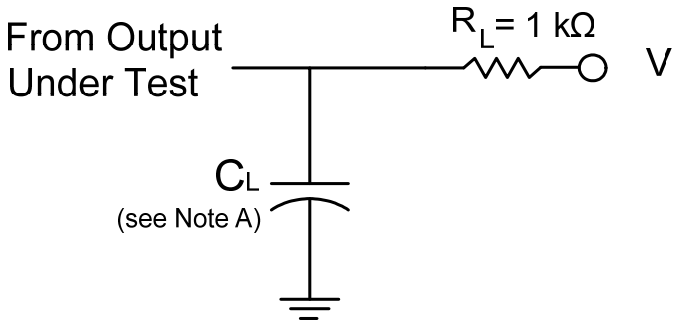
Symbol	Parameter	Min	Typ	Max	Unit
$V_{OL(p)}$	Quiet output, maximum dynamic V_{OL}	—	0.2	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}	—	-0.1	-0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}	—	3.1	—	V
$V_{IH(D)}$	High Level dynamic input voltage	2.31	—	—	V
$V_{IL(D)}$	Low Level dynamic input voltage	—	—	0.99	V

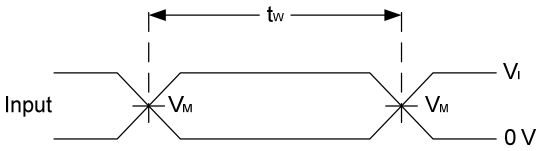
Package Characteristics

Symbol	Parameter	Test Conditions	V_{CC}	Min	Typ	Max	Unit
C_i	Input Capacitance	V_i = V_{CC} – or GND	2.0 to 5.5V	—	3.3	10	pF

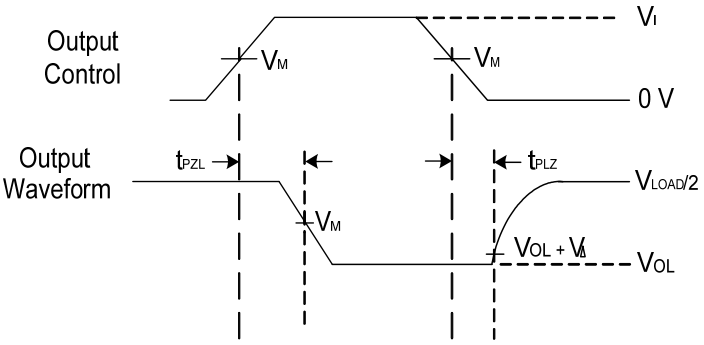
NEW PRODUCT

Parameter Measurement Information





Voltage Waveform
Pulse Duration



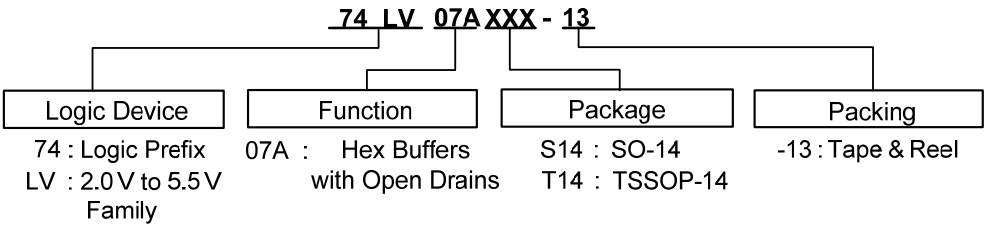
Voltage Waveform
Propagation Delay Times

Notes:
A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
C. The inputs are measured one at a time with one transition per measurement.
D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD}.
E. t_{PZL} is measured at V_M.
D. t_{PLZ} is measured at V_{OL} +V_Δ where V_Δ = 0.3V.

Figure 1 Load Circuit and Voltage Waveforms

NEW PRODUCT

Ordering Information

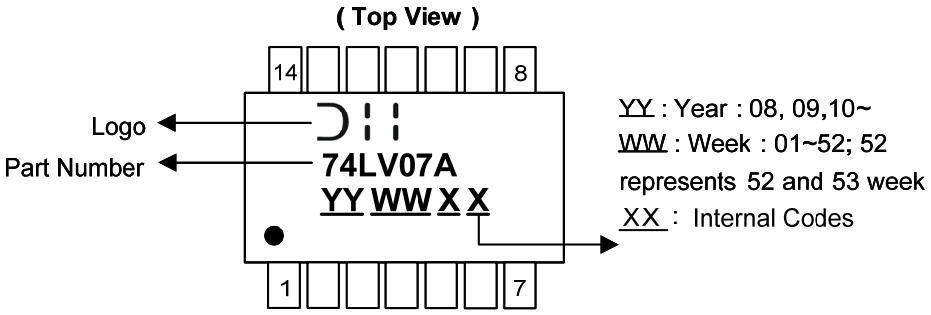


Device	Package Code	Packaging (Note 6)	13" Tape and Reel	
			Quantity	Part Number Suffix
74LV07AS14-13	S14	SO-14	2500/Tape & Reel	-13
74LV07AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Note: 6. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO14, TSSOP14



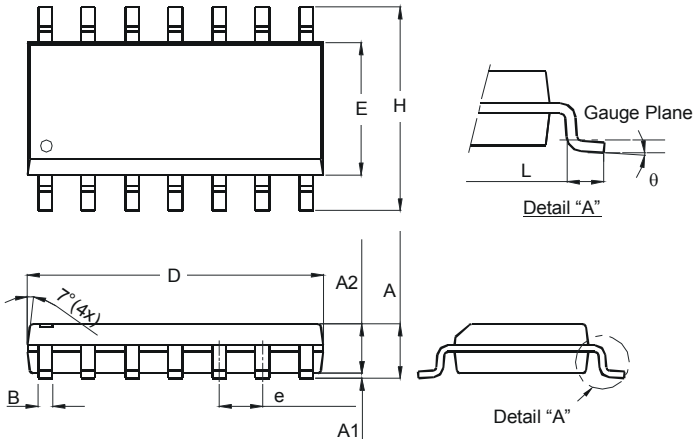
Part Number	Package
74LV07AS14	SO-14
74LV07AT14	TSSOP-14

NEW PRODUCT

Package Outline Dimensions (All Dimensions in mm)

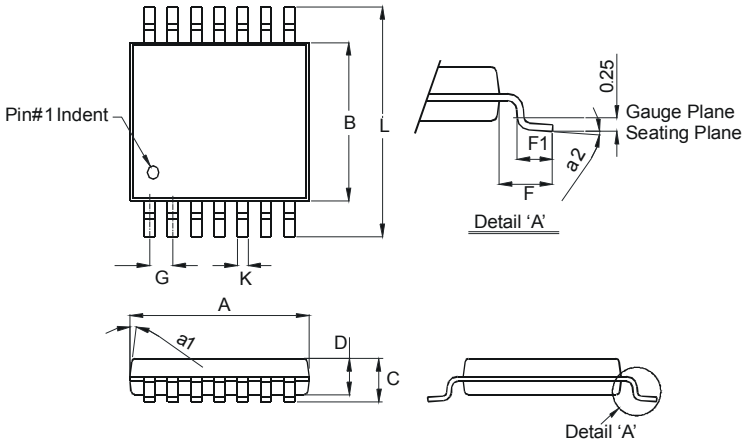
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



SO-14		
Dim	**Min**	**Max**
A	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
B	0.33	0.51
D	8.53	8.74
E	3.80	3.99
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14



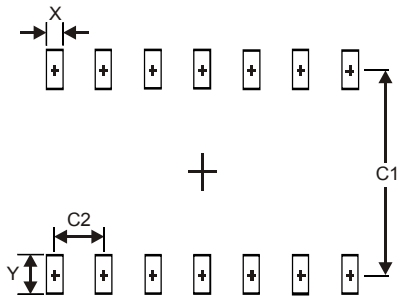
TSSOP-14		
Dim	**Min**	**Max**
a1	7° (4X)	
a2	0°	8°
A	4.9	5.10
B	4.30	4.50
C	—	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		

NEW PRODUCT

Suggested Pad Layout

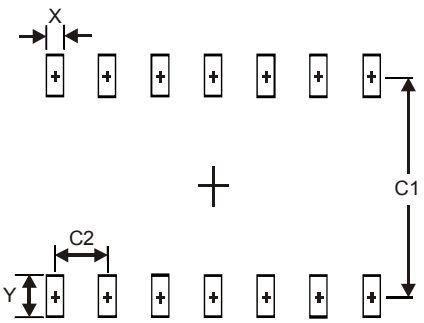
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65

NEW PRODUCT

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or

2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

www.diodes.com